# **Chlorine-Enabled Electron Doping in Solution-Synthesised SnSe Thermoelectric Nanomaterials; Supporting Information.**

Guang Han,<sup>a</sup> Srinivas R. Popuri,<sup>b</sup> Heather F. Greer,<sup>c</sup> Lourdes F. Llin,<sup>d</sup> Jan-Willem G. Bos,<sup>b</sup> Wuzong Zhou,<sup>c</sup> Douglas J. Paul,<sup>d</sup> Hervé Ménard,<sup>e</sup> Andrew R. Knox,<sup>d</sup> Andrea Montecucco,<sup>d</sup> Jonathan Siviter,<sup>d</sup> Elena A. Man,<sup>d</sup> Wen-guang Li,<sup>d</sup> Manosh C. Paul,<sup>d</sup> Min Gao,<sup>f</sup> Tracy Sweet,<sup>f</sup> Robert Freer,<sup>g</sup> Feridoon Azough,<sup>g</sup> Hasan Baig,<sup>h</sup> Tapas K. Mallick,<sup>h</sup> and Duncan H. Gregory<sup>a\*</sup>

<sup>a</sup>WestCHEM, School of Chemistry, University of Glasgow, Glasgow, G12 8QQ, UK

<sup>b</sup>Institute of Chemical Sciences and Centre for Advanced Energy Storage and Recovery, School of

Engineering and Physical Sciences, Heriot-Watt University, Edinburgh, EH14 4AS, UK

°EaStCHEM, School of Chemistry, University of St Andrews, St Andrews, Fife KY16 9ST, UK

<sup>d</sup>School of Engineering, University of Glasgow, Glasgow, G12 8QQ, UK

<sup>e</sup>Sasol (UK) Ltd, St Andrews, KY16 9ST, UK

<sup>f</sup>School of Engineering, Cardiff University, Cardiff, CF24 3AA, UK

<sup>g</sup>School of Materials, University of Manchester, Manchester, M13 9PL, UK

<sup>h</sup>Environment and Sustainability Institute, University of Exeter, Penryn Campus, Penryn TR10 9FE

UK

\*Corresponding author: Email: <u>Duncan.Gregory@glasgow.ac.uk</u>

### Experimental details

Materials Synthesis. In a typical synthesis of SnSe nanoparticles, 260 mmol citric acid (Alfa, 99.5%) and 10 mmol SnCl<sub>2</sub>·2H<sub>2</sub>O (Sigma, 99.99%) were added into 50 ml deionised water (DIW) within a two-neck round-bottom flask to yield a transparent solution. In parallel, 10 mmol Se (Aldrich, >99.5%) and 20 mmol NaBH<sub>4</sub> (Alfa, 98%) were added to 50 ml DIW within a single-neck roundbottom flask, to prepare a transparent NaHSe solution (2Se + 4NaBH<sub>4</sub> + 7H<sub>2</sub>O  $\rightarrow$  2NaHSe +  $Na_2B_4O_7 + 14H_2\uparrow$ ). After the SnCl<sub>2</sub>-citric acid solution was heated to its boiling temperature using an oil bath, the freshly prepared 50 ml NaHSe aqueous solution was injected into the solution, leading to the immediate formation of a black precipitate. The mixture was heated to boiling again, held for either 1 min, 5 min, 2 h or 24 h and allowed to cool to room temperature under Ar (BOC, 99.998%) on a Schlenk line. The products were collected by centrifuge, washed with DIW and ethanol several times, and dried in ambient atmosphere at 50 °C for 12 h. Scaled-up syntheses were performed with 5.5-fold precursor concentrations, i.e. using 1430 mmol citric acid, 55 mmol  $SnCl_2 \cdot 2H_2O$ , and 275 ml NaHSe solution (0.2 mol L<sup>-1</sup>); the products demonstrated phase purity and morphology identical to the products synthesised at lower precursor concentrations. For the surfactant-free synthesis of SnSe nanoparticles, 4 ml hydrochloric acid (Sigma, 36.5-38%) was introduced into SnCl<sub>2</sub> solution in place of 50 g citric acid, while the other experimental conditions were unchanged. The synthesised samples used for characterisation and performance evaluation were stored in an Ar-filled MBraun glove box (< 0.5 ppm  $H_2O_1$  < 0.5 ppm  $O_2$ ) to avoid possible reaction with ambient air.

Materials Characterisation and Performance Evaluation. The phase composition and crystal structures of the as-prepared samples were investigated by powder X-ray diffraction (PXD), using a PANalytical X'pert Pro MPD diffractometer in Bragg-Brentano geometry (Cu K $\alpha_1$  radiation,  $\lambda = 1.5406$  Å). Diffraction data were collected at room temperature with a step size of 0.017° over  $10^\circ \le 20 \le 90^\circ$  for 1 h (for phase indexing) or over  $10^\circ \le 20 \le 100^\circ$  for 8-12 h (for structural refinement).

*In-situ* variable-temperature PXD measurements were performed on a 2 h solution-synthesised sample that was loaded into a sample holder under ambient atmosphere. The sample was heated to the selected temperatures under a constant Ar flow (BOC, 99.998%) using an Anton Paar HK1200N high-temperature cell with Kapton windows. The sample was progressively heated from room temperature to 700 K in steps of 50 K at a rate of 5 K min<sup>-1</sup> and the PXD patterns were collected at each temperature with a step size of 0.017° from  $10^{\circ} \le 20 \le 85^{\circ}$  over a period of 1 h. The sample was subsequently cooled to 500 K and then 300 K at a rate of ~10 K min<sup>-1</sup> under Ar flow and PXD data were collected at each temperature. The crystal structures of the synthesised products were refined using the Rietveld method against PXD data with the GSAS and EXPGUI software packages<sup>[1]</sup> and the previously published SnSe,<sup>[2]</sup> SnSe<sub>2</sub>,<sup>[3]</sup> and SnO<sub>2</sub><sup>[4]</sup> structures as a basis. For Rietveld refinement against PXD data of pellet samples, a shifted Chebyschev function (type 1 within GSAS) and a Pseudo-Voigt profile function (type 2 within GSAS) were applied to model the background and peak shape respectively, and a March-Dollase preferred orientation parameter along (400) of SnSe and (001) of SnSe<sub>2</sub> was introduced and refined.

The morphological and chemical characteristics of the synthesised products were investigated by scanning electron microscopy (SEM, Carl Zeiss Sigma, 5 and 20 kV for imaging and elemental analyses, respectively), equipped with energy-dispersive X-ray spectroscopy (EDS, Oxford Instruments X-Max 80). The synthesised powders were spread on a conductive carbon tape that was then mounted on a standard SEM sample stub. Microstructure, crystal structure and chemical composition were further characterised by transmission electron microscopy (TEM) using an FEI Titan Themis 200 electron microscope equipped with an X-FEG Schottky field emission gun and a Super-X windowless EDS detector, and a JEOL JEM-2011 electron microscope fitted with a LaB<sub>6</sub> filament, both operating at an accelerating voltage of 200 kV. TEM images, high resolution TEM (HRTEM) images and selected area electron diffraction (SAED) patterns were recorded using an FEI Ceta 16-megapixel CMOS camera (FEI Titan Themis 200) and a Gatan 794 Multiscan CCD camera (JEOL JEM-2011). To prepare TEM samples from SnSe pellets, SnSe powders were peeled

from the pellet surface using a blade followed by a gentle crushing using mortar and pestle. The peeled SnSe powders or solution-synthesised SnSe powders were dispersed in ethanol by sonication for 30 s to obtain a uniform dispersion. 2-5 drops of the suspension were dropped on to a 3 mm diameter holey C-coated Cu TEM grid.

As-synthesised SnSe samples were directly mounted in a Fourier transform infrared (FTIR) spectrophotometer (Shimadzu, FTIR-8400S) to obtain FTIR spectra at room temperature. Thermogravimetric-differential thermal analysis (TG-DTA) of the samples was performed using a Netzsch STA 409 thermal analyser located in an Ar-filled MBraun glove box (< 0.1 ppm H<sub>2</sub>O, < 0.1 ppm O<sub>2</sub>). Approximately 25 mg of SnSe pellet or powder was heated to 700 °C in an alumina pan under flowing Ar at a heating rate of 5 °C min<sup>-1</sup>. For optical bandgap measurement, SnSe powders were spread into a thin uniform layer on a layer of BaSO<sub>4</sub> powder, and diffuse reflectance UV-Vis (DR-UV-Vis) spectra were measured using a UV-Vis spectrophotometer (Shimadzu, UV-2600) within a wavelength range of 400-1300 nm. The XPS experiments were performed using a Kratos Axis Ultra-DLD photoelectron spectrometer with an Al monochromatic X-ray source. The data were analysed using CasaXPS software.

To measure the electrical performance of SnSe nanostructures, SnSe powder was loaded into a graphite die and hot-pressed into dense pellets (relative density of > 85%) at 500 °C for 20 min under Ar protection with a uniaxial pressure of ~60 MPa. The obtained pellets were cut into bars with dimensions of 12 mm x 3 mm x 2 mm, and the Seebeck coefficient and electrical conductivity of the SnSe bars were measured perpendicular to the hot pressing direction using a Linseis LSR-3 instrument under a helium atmosphere within a temperature range of 300-540 K. The uncertainty in the measurement of the Seebeck coefficient and electrical conductivity is 5%, leading to ~10% uncertainty for the thermoelectric power factor measurement. Thermal diffusivity (*D*) of circular pellets (diameter 13 mm; thickness 2 mm) was measured using a Linseis LFA 1000 instrument from 300 - 540 K and thermal conductivity ( $\kappa$ ) was calculated using  $\kappa = DC_p\rho$ , where  $C_p$  and  $\rho$  are specific heat capacity and density, respectively.  $C_p$  values for pellets were calculated from the weighted average of the reported values of  $C_p$  for SnSe,<sup>[5]</sup> SnSe<sub>2</sub><sup>[6]</sup> and SnO<sub>2</sub><sup>[7]</sup> (where the respective weightings were determined from the refined phase fractions from the Rietveld refinements against PXD data). Hall effect measurements perpendicular to the hot pressing direction were performed on a Nanometrics HL5500 Hall system using a Van der Pauw configuration. The pellets were shaped into 5 mm x 5 mm squares with a thickness of 2 mm. Silver contacts were placed at the edges of the surface sample with a size of 500 µm x 500 µm. The Hall coefficient ( $R_H$ ) and electrical resistivity ( $\rho_H$ ) were measured directly by the Hall system. Hall carrier density ( $n_H$ ) and mobility ( $\mu_H$ ) were calculated using  $n_H = (eR_H)^{-1}$  and  $\mu_H = R_H/\rho_H$ , where *e* is the electron charge.

#### **Oxidation Experiments**

Three experiments were designed and performed in an effort to understand the origins of the oxidation process further. First, we subjected the SnSe nanoparticles (samples prepared for 1 min, 2 h and 24 h) to TG-DTA (Figure S8) (Netzsch STA 409 instrument located in an Ar-filled MBraun glove box with < 0.1 ppm H<sub>2</sub>O, < 0.1 ppm O<sub>2</sub>). PXD analysis (Figure S9) of the post-TG-DTA samples reveals that a small amount of SnO<sub>2</sub> was produced and this amount increases as the solution reaction duration decreases. Considering that SnSe nanoparticles are apparently coated with higher concentrations of citric acid (Figure S10) at shorter reaction durations and higher weight losses (corresponding to oxidation) were observed for these shorter-duration samples, it is tempting to infer that the carboxylic groups bound to the surface contribute to SnO<sub>2</sub> formation (as indicated by the exothermic DTA peak at ~330 °C; Figure S8).<sup>[8]</sup> The excess Se generated from the formation of SnO<sub>2</sub> volatilises as evidenced by the significant weight decrease between 500 and 700 °C (Figure S8); therefore, no SnSe<sub>2</sub> phase was detected in the PXD patterns of the TG-DTA products as might be expected as a result of equation S1 below:

$$SnSe + O_2 \rightarrow SnO_2 + Se \uparrow$$
 (S1)

In a second experiment, we prepared SnSe nanoparticles using a similar solution method replacing citric acid with hydrochloric acid in reactions of either 2 h or 24 h duration (Figures S11, S12; Table S4). We hot pressed these surfactant-free nanoparticles into pellets (denoted as **SF1** and **SF2**) and PXD patterns again indicate the presence of SnO<sub>2</sub> and SnSe<sub>2</sub> as secondary phases to SnSe (Figures S13, S14; Tables S5, S6). This suggests that the surfaces of the small nanoparticles may adsorb O<sub>2</sub> thus leading in turn to oxidation to SnO<sub>2</sub>. As hot pressing was performed in enclosed dies, the Se byproduct (following formation of SnO<sub>2</sub>) is not released from the system as in the TG-DTA experiment (above) and leads to the formation of the Se-rich phase SnSe<sub>2</sub>.

Finally, to probe the formation process of SnSe<sub>2</sub> and SnO<sub>2</sub> during heating of SnSe nanoparticles, we performed *in-situ* variable temperature PXD experiments with 2 h-synthesised SnSe nanoparticles. The powder was loaded into a PXD holder (under air) and heated under an Ar gas flow so as to simulate the environmental conditions of the hot pressing process applied in this study (Figure S15). As can be seen, crystalline SnSe<sub>2</sub> and SnO<sub>2</sub> start to form at approximately 500 K and 600 K, respectively. The Bragg peak width of SnSe decreased notably by 700 K, indicating the increased particle size. Moreover, it is assumed that sublimation of Se took place at 650-700 K, leading to the decreased relative intensity of SnSe<sub>2</sub>. Following Se sublimation on cooling, the final products that dominate the diffractogram are principally SnSe and SnO<sub>2</sub> as a minor phase, which is approximately consistent with the PXD analysis of post-TG-DTA products above. Therefore, the experimental evidence would suggest that SnO<sub>2</sub> forms both as a result of desorbing and reacting surface carboxylate groups<sup>[8]</sup> and from the reaction of the very small, high surface area nanoparticles with adventitious O<sub>2</sub>.<sup>[9]</sup> It should be noted that reports of oxidation also exist for solution-synthesised PbTe nanowires and Bi<sub>2</sub>Te<sub>3</sub> nanoparticles that were subsequently pressed at high temperature,<sup>[10]</sup> and SnO<sub>2</sub> precipitates were observed in SnSe pellets that were consolidated by spark plasma sintering from fine SnSe powders (prepared by mechanical alloying).<sup>[9]</sup>



**Figure S1.** Digital photographs showing (a) the nanoparticle solution after a synthesis and (b) a typical yield of SnSe nanoparticles (~10.4 g, *ca.* 96 %) produced in a one-pot synthesis.



**Figure S2.** (a,b) SEM images; (c) EDS spectrum; (d) TEM image of SnSe nanoparticles synthesised after 2 h of heating.



**Figure S3.** PXD patterns of SnSe nanoparticles synthesised after 1 min, 5 min, 2 h and 24 h of heating respectively, with all reflections indexed to orthorhombic SnSe: (a) scans from  $20 \le 2\theta/^{\circ} \le$  70 and (b) detail of the (201), (011), (111) and (400) Bragg peaks.



**Figure S4.** Profile plots from Rietveld refinement against PXD data for SnSe nanoparticles synthesised after (a) 1 min, (b) 5 min and (c) 24 h.



**Figure S5.** SEM characterisation of SnSe nanoparticles synthesised after (a,d,g) 1 min, (b,e,h) 5 min and (c,f,i) 24 h of heating: (a-f) SEM images; (g-i) EDS spectra.



**Figure S6.** (a) TEM image; (b) SAED pattern and (c,d) HRTEM images of SnSe nanoparticles synthesised after 5 min of heating.



Figure S7. Profile plot from Rietveld refinement against PXD data for SnSe pellet 1.



**Figure S8.** TG-DTA profiles of SnSe powders synthesised with different durations: (a) 1 min, (b) 2 h and (c) 24 h. The exothermic peak at ~330 °C and endothermic peak at ~560 °C correspond to the formation of  $SnO_2$  (likely arising from the decomposition of carboxylic groups at the material surface) and volatilisation of Se, respectively.



**Figure S9.** PXD patterns of post-TG-DTA products from heating SnSe nanoparticles to 700 °C under an Ar flow.



Figure S10. FTIR spectra of SnSe nanoparticles synthesised with different heating durations.



**Figure S11.** Profile plots from Rietveld refinement against PXD data for SnSe nanoparticles synthesised after (a) 2 h and (b) 24 h using hydrochloric acid in place of citric acid.



**Figure S12.** SEM characterisation of SnSe nanoparticles synthesised after (a,c) 2 h, (b,d) 24 h of heating using hydrochloric acid (to replace citric acid): (a,b) SEM images; (c,d) EDS spectra. The average particle sizes are 45 and 70 nm for the reaction duration of 2 and 24 h respectively, which are much larger compared to their counterparts synthesised using citric acid as the surfactant.



Figure S13. Profile plots from Rietveld refinement against PXD data for the SnSe pellets (a) SF1 and (b) SF2.



**Figure S14.** SEM characterisation of SnSe pellet (a,c) **SF1** and (b,d) **SF2**: (a,b) SEM images; (c,d) EDS spectra.



**Figure S15.** *In-situ* variable temperature PXD patterns of 2 h solution-synthesised SnSe nanoparticles collected at the temperatures indicated.



**Figure S16.** PXD patterns of **1** and **3** collected with the pellet faces (a) perpendicular and (b) parallel to the hot pressing direction, respectively.



**Figure S17.** (a,b) Secondary electron (SE) SEM image; (c) EDS spectrum; (d) back scattered electron (BSE) SEM image and (e-g) element mapping for Sn (green), Se (red) and Cl (white) in (c), respectively for pellet **1**.



**Figure S18.** TEM characterisation of SnSe pellet 1: (a) typical TEM image of peeled powders; (b) SAED pattern collected from a number of plates and nanoparticles; (c) HRTEM image of an SnSe plate; (d) HRTEM image of an SnSe<sub>2</sub> plate and (e) HRTEM image a cluster of SnO<sub>2</sub> nanoparticles and SnSe plates. Selected d-spacings are indicated.



**Figure S19.** TG-DTA profiles of SnSe pellets: (a) **1**, (b) **3** and (c) **4**. The endothermic peak at ~630 °C corresponds to volatilisation of Se.



Figure S20. Profile plots from Rietveld refinement against PXD data for SnSe pellets (a) 2, (b) 3 and (c) 4.



**Figure S21.** TEM characterisation of SnSe pellet **3**: (a) TEM image; (b) HRTEM image revealing SnO<sub>2</sub> nanoparticles distributed in SnSe plate.



**Figure S22.** SEM characterisation of SnSe pellets (a,d,g) **2**, (b,e,h) **3** and (c,f,i) **4**: (a-f) SEM images; (g-i) EDS spectra.



**Figure S23.** XPS analysis of SnSe pellet **3**: (a) survey scan; (b-d) high-resolution scan for Cl 2p, Sn 3d and Se 3d, respectively.

The high-resolution XPS spectrum of Sn (Figure S23c) shows two peak values of Sn  $3d_{5/2}$ : the binding energy of 486.9 eV can be rationalised in terms of Sn<sup>2+</sup> bonded to Cl<sup>-[11]</sup> and/or the bonding of Sn<sup>4+</sup> to Se<sup>2-[12]</sup> and O<sup>2-,[13]</sup> while the binding energy of 485.5 eV corresponds to Sn<sup>2+</sup> bonded to Se<sup>2-[14]</sup>. The high-resolution XPS spectrum of Se (Figure S23d) demonstrates two peak values of Se  $3d_{5/2}$ . The peak with a binding energy of 53.9 eV corresponds to Se<sup>2-</sup> bonded to Sn<sup>2+[14]</sup> and Sn<sup>4+[12]</sup>. The peak at higher binding energy of 55.0 eV indicates that the surface Se<sup>2-</sup> was partially oxidised. Considering that the Se  $3d_{5/3}$  of Se<sup>0</sup> has a binding energy of ~55.6 eV, this oxidised species could be Se<sub>2</sub><sup>2-,[15]</sup> For the Cl 2p envelope, the area ratio of 1:2 for the two spin orbit peaks was used, an equal FWHM and a peak separation of 1.60 eV. According to quantitative XPS analysis, the Sn:Se:Cl atomic ratio is 53.3:43.5:3.2.



**Figure S24.**  $[F(R)hv]^{1/2}$  vs energy plots from DR-UV-Vis spectroscopy data for SnSe pellets (1-4).



**Figure S25.** Repeat electrical property measurements on SnSe pellets: (a-c) **1**, (d-f) **3**, (g-i) **SF1**, (j-l) **SF2** showing the variation of: (a,d,g,j) electrical conductivity ( $\sigma$ ), (b,e.h,k) Seebeck coefficient (*S*) and (c,f,i,l) power factor ( $S^2\sigma$ ) as a function of temperature.

**1** and **3** exhibit no evidence of hysteresis upon cooling and have repeatable electrical performance during cycling tests (Figures S25a-f). In contrast, **SF1** and **SF2**, show hysteresis in the temperature dependence of the Seebeck coefficient and power factor on the first cooling cycle, although they demonstrate a repeatable electrical performance under subsequent cycling (Figure S25g-l). This confirms that our *in-situ* Cl doping strategy is capable of producing n-type SnSe materials with highly consistent and repeatable thermoelectric performance.



**Figure S26.** Thermal properties of pellet **1** and **4**, showing: (a) thermal diffusivity (*D*); (b) calculated specific heat capacity ( $C_p$ ) and (c) thermal conductivity ( $\kappa$ ) as a function of temperature; (d) a comparison of measured  $\kappa$  with selected literature values for polycrystalline n-type SnSe<sub>0.95</sub>-0.2mol% BiCl<sub>3</sub>,<sup>[16]</sup> p-type SnSe,<sup>[17]</sup> and n-type SnSe with varying I-doping concentrations;<sup>[17]</sup> (e) a comparison of measured  $\kappa$  with values for single crystalline p-type SnSe<sup>[5]</sup> and Sn<sub>0.985</sub>Na<sub>0.015</sub>Se.<sup>[18]</sup>

Heating duration	1 min	5 min	2 h	24 h
Chemical Formula	SnSe	SnSe	SnSe	SnSe
Crystal System	Orthorhombic	Orthorhombic	Orthorhombic	Orthorhombic
Space Group	Pnma	Pnma	Pnma	Pnma
<i>a</i> (Å)	11.5514(38)	11.5429(24)	11.5424(8)	11.5369(5)
<i>b</i> (Å)	4.1954(14)	4.1816(11)	4.1775(4)	4.1714(2)
<i>c</i> (Å)	4.3350(18)	4.3692(13)	4.3841(5)	4.4009(3)
Volume (Å <sup>3</sup> )	210.08(18)	210.89(13)	211.40(4)	211.80(3)
Z	4	4	4	4
Formula Weight (g mol <sup>-1</sup> )	197.65	197.65	197.65	197.65
Calculated density (g cm <sup>-3</sup> )	6.249	6.225	6.210	6.199
R <sub>wp</sub>	0.0927	0.0947	0.0692	0.0760
R <sub>p</sub>	0.0711	0.0715	0.0500	0.0533
$\chi^2$	1.241	1.311	4.493	8.074

 Table S1 Crystallographic data for SnSe nanoparticles synthesised with different heating durations.

 Table S2 Atomic parameters for SnSe nanoparticles synthesised after 2 h heating

Atom	Wyckoff symbol	Х	у	Z	100*U <sub>iso</sub>	Occupancy
					$(Å^2)$	
Sn	4c	0.12489(19)	0.25000	0.08481(39)	5.67(8)	1
Se	4c	0.36228(27)	0.25000	0.00660(46)	3.02(8)	1

### Table S3 Crystallographic data for pellet 1

Chemical Formula	SnSe <sub>0.988</sub> Cl <sub>0.012</sub>	SnSe <sub>2</sub>	SnO <sub>2</sub>
Crystal System	Orthorhombic	Trigonal	Tetragonal
Space Group	Pnma (62)	P-3m1 (164)	P 42/m n m (136)
<i>a</i> (Å)	11.5551(8)	2 9107(10)	4 7412(9)
<i>b</i> (Å)	4.1968(7)	5.0107(19)	4.7413(8)
<i>c</i> (Å)	4.3785(7)	6.1570(14)	3.1911(8)
Volume (Å <sup>3</sup> )	212.33(4)	77.43(6)	71.73(3)
Z	4	1	2
Formula Weight (g mol <sup>-1</sup> )	197.12	276.61	150.69
Calculated density (g cm <sup>-3</sup> )	6.166	5.932	6.976
Phase weight percentage (wt.%)	79.15(11)	11.06(25)	9.79(16)
R <sub>wp</sub>	0.0703		
R <sub>p</sub>	0.0468		
$\chi^2$		8.088	

**Table S4** Crystallographic data for SnSe nanoparticles synthesised using hydrochloric acid(replacing citric acid and heating for 2 and 24 h respectively)

Reaction duration	2 h	24 h
Chemical Formula	SnSe	SnSe
Crystal System	Orthorhombic	Orthorhombic
Space Group	Pnma	Pnma
<i>a</i> (Å)	11.5476(7)	11.5404(6)
<i>b</i> (Å)	4.1817(4)	4.1743(3)
<i>c</i> (Å)	4.3770(4)	4.3926(4)
Volume (Å <sup>3</sup> )	211.36(4)	211.61(3)
Z	4	4
Formula Weight (g mol <sup>-1</sup> )	197.65	197.65
Calculated density (g cm <sup>-3</sup> )	6.211	6.204
$R_{wp}$	0.0643	0.0783
R <sub>p</sub>	0.0464	0.0554
$\chi^2$	5.570	8.697

 $Table \ S5 \ Crystallographic \ data \ for \ pellet \ SF1$ 

Chemical Formula	SnSe <sub>0.994</sub> Cl <sub>0.006</sub>	SnSe <sub>2</sub>	SnO <sub>2</sub>
Crystal System	Orthorhombic	Trigonal	Tetragonal
Space Group	Pnma (62)	P-3m1 (164)	P 42/m n m (136)
<i>a</i> (Å)	11.5576(7)	2 7995(26)	4 7402(11)
<i>b</i> (Å)	4.2013(5)	5.7883(30)	4.7402(11)
<i>c</i> (Å)	4.3710(6)	6.1601(18)	3.1931(12)
Volume (Å <sup>3</sup> )	212.24(3)	76.57(11)	71.75(4)
Z	4	1	2
Formula Weight (g mol <sup>-1</sup> )	197.65	276.61	150.69
Calculated density (g cm <sup>-3</sup> )	6.185	5.998	6.975
Phase weight percentage (wt.%)	85.40(6)	6.66(23)	7.94(14)
R <sub>wp</sub>		0.0766	
R <sub>p</sub>	0.0548		
$\chi^2$	6.991		

Chemical Formula	SnSe <sub>0.998</sub> Cl <sub>0.002</sub>	SnSe <sub>2</sub>	SnO <sub>2</sub>
Crystal System	Orthorhombic	Trigonal	Tetragonal
Space Group	Pnma (62)	<i>P-3m1 (164)</i>	P 42/m n m (136)
<i>a</i> (Å)	11.5574(6)	2 7057(24)	4 7420(18)
<i>b</i> (Å)	4.2023(4)	5.7957(34)	4.7450(16)
<i>c</i> (Å)	4.3677(4)	6.1579(24)	3.2019(21)
Volume (Å <sup>3</sup> )	212.13(3)	76.83(11)	72.03(6)
Z	4	1	2
Formula Weight (g mol <sup>-1</sup> )	197.56	276.61	150.69
Calculated density (g cm <sup>-3</sup> )	6.186	5.978	6.948
Phase weight percentage (wt.%)	87.71(5)	6.84(23)	5.46(14)
R <sub>wp</sub>	0.0789		
R <sub>p</sub>	0.0582		
$\chi^2$		7.369	

# Table S6 Crystallographic data for pellet SF2

 Table S7 Crystallographic data for pellet 2

Chemical Formula	SnSe <sub>0.975</sub> Cl <sub>0.025</sub>	SnSe <sub>2</sub>	SnO <sub>2</sub>
Crystal System	Orthorhombic	Trigonal	Tetragonal
Space Group	Pnma (62)	P-3m1 (164)	P 42/m n m (136)
<i>a</i> (Å)	11.5579(9)	2 8107(15)	4 7412(0)
<i>b</i> (Å)	4.1991(7)	5.8107(15)	4.7413(9)
<i>c</i> (Å)	4.3749(7)	6.1573(13)	3.1904(9)
Volume (Å <sup>3</sup> )	212.33(4)	77.43(5)	71.72(3)
Z	4	1	2
Formula Weight (g mol <sup>-1</sup> )	196.56	276.61	150.69
Calculated density (g cm <sup>-3</sup> )	6.149	5.932	6.978
Phase weight percentage (wt.%)	71.57(15)	14.62(25)	13.81(18)
R <sub>wp</sub>	0.0944		
R <sub>p</sub>	0.0665		
χ <sup>2</sup>	11.66		

### Table S8 Crystallographic data for pellet 3

Chemical Formula	SnSe0.985Cl0.015	SnSe <sub>2</sub>	SnO <sub>2</sub>
Crystal System	Orthorhombic	Trigonal	Tetragonal
Space Group	Pnma (62)	P-3m1 (164)	P 42/m n m (136)
<i>a</i> (Å)	11.5583(8)	2 8110(17)	4 7412(10)
<i>b</i> (Å)	4.2026(7)	3.8110(17)	4.7412(10)
<i>c</i> (Å)	4.3691(6)	6.1559(1)	3.1903(11)
Volume (Å <sup>3</sup> )	212.23(4)	77.43(6)	71.71(4)
Z	4	1	2
Formula Weight (g mol <sup>-1</sup> )	197.02	276.61	150.69
Calculated density (g cm <sup>-3</sup> )	6.166	5.932	6.978
Phase weight percentage (wt.%)	71.73(14)	15.28(25)	13.00(18)
R <sub>wp</sub>	0.0984		
R <sub>p</sub>	0.0677		
$\chi^2$		7.648	

Chemical Formula	SnSe0.994Cl0.006	SnSe <sub>2</sub>	SnO <sub>2</sub>
Crystal System	Orthorhombic	Trigonal	Tetragonal
Space Group	Pnma (62)	<i>P-3m1 (164)</i>	P 42/m n m (136)
<i>a</i> (Å)	11.5421(5)	2 9110(24)	1 7625(20)
<i>b</i> (Å)	4.1909(4)	5.0119(54)	4.7053(50)
<i>c</i> (Å)	4.3861(4)	6.1534(16)	3.1968(34)
Volume (Å <sup>3</sup> )	212.16(3)	77.43(11)	72.54(10)
Z	4	1	2
Formula Weight (g mol <sup>-1</sup> )	197.38	276.61	150.69
Calculated density (g cm <sup>-3</sup> )	6.179	5.932	6.899
Phase weight percentage (wt.%)	90.41(4)	6.08(21)	3.51(16)
R <sub>wp</sub>	0.0867		
R <sub>p</sub>	0.0620		
$\chi^2$		5.880	

# Table S9 Crystallographic data for pellet 4

#### **References:**

- a) A. C. Larson, R. B. Von Dreele, General Structure Analysis System (GSAS); Los Alamos National Laboratory Report LAUR 86-748; Los Alamos National Laboratory, 1994; b) B. H. Toby, J. Appl. Crystallogr. 2001, 34, 210-213.
- [2] A. S. Avilov, R. M. Imamov, S. N. Navasardyan, *Kristallografiya* 1979, 24, 874-875.
- [3] F. A. S. Al-Alamy, A. A. Balchin, M. White, J. Mater. Sci. 1977, 12, 2037-2042.
- [4] W. H. Baur, A. A. Khan, Acta Crystallogr. Sect. B 1971, 27, 2133-2139.
- [5] L. D. Zhao, S. H. Lo, Y. S. Zhang, H. Sun, G. J. Tan, C. Uher, C. Wolverton, V. P. Dravid, M. G. Kanatzidis, *Nature* 2014, 508, 373-377.
- [6] H. Wiedemeier, G. Pultz, U. Gaur, B. Wunderlich, *Thermochim. Acta* 1981, 43, 297-303.
- [7] H. Gamsjäger, T. Gajda, J. Sangster, S. Saxena, W. Voigt, in *Nuclear Energy Agency Data* Bank, Organisation for Economic Co-operation and Development (Ed.), Vol. 12, 2012.
- [8] M. Ibáñez, R. J. Korkosz, Z. S. Luo, P. Riba, D. Cadavid, S. Ortega, A. Cabot, M. G. Kanatzidis, J. Am. Chem. Soc. 2015, 137, 4046-4049.
- [9] Y.-X. Chen, Z.-H. Ge, M. Yin, D. Feng, X.-Q. Huang, W. Zhao, J. He, *Adv. Funct. Mater.* 2016, *26*, 6836-6845.
- [10] a) S. W. Finefrock, G. Zhang, J.-H. Bahk, H. Fang, H. Yang, A. Shakouri, Y. Wu, *Nano Lett.* 2014, *14*, 3466-3473; b) C. Kim, D. H. Kim, H. Kim, J. S. Chung, *ACS Appl. Mater. Interfaces* 2012, *4*, 2949-2954; c) H. F. He, X. F. Li, Z. Q. Chen, Y. Zheng, D. W. Yang, X. F. Tang, *J. Phys. Chem. C* 2014, *118*, 22389-22394.
- [11] H. Willemen, D. F. Van De Vondel, G. P. Van Der Kelen, Inorg. Chim. Acta 1979, 34, 175-180.
- [12] C. H. de Groot, C. Gurnani, A. L. Hector, R. M. Huang, M. Jura, W. Levason, G. Reid, *Chem. Mater.* 2012, 24, 4442-4449.
- [13] W. K. Choi, H. J. Jung, S. K. Koh, J. Vac. Sci. Technol. A 1996, 14, 359-366.
- [14] M. A. Franzman, C. W. Schlenker, M. E. Thompson, R. L. Brutchey, J. Am. Chem. Soc. 2010, 132, 4060-4061.
- [15] X. M. Zhou, P. Gao, S. C. Sun, D. Bao, Y. Wang, X. B. Li, T. T. Wu, Y. J. Chen, P. P. Yang, *Chem. Mater.* 2015, 27, 6730-6736.
- [16] X. Wang, J. T. Xu, G. Q. Liu, Y. J. Fu, Z. Liu, X. J. Tan, H. Z. Shao, H. C. Jiang, T. Y. Tan, J. Jiang, *Appl. Phys. Lett.* 2016, *108*, 083902.
- [17] Q. Zhang, E. K. Chere, J. Y. Sun, F. Cao, K. Dahal, S. Chen, G. Chen, Z. F. Ren, Adv. Energy Mater. 2015, 5, 1500360.
- [18] L.-D. Zhao, G. Tan, S. Hao, J. He, Y. Pei, H. Chi, H. Wang, S. Gong, H. Xu, V. P. Dravid, C. Uher, G. J. Snyder, C. Wolverton, M. G. Kanatzidis, *Science* 2015, 351, 141-144.